

20 V, dual P-channel Trench MOSFET 28 June 2016

Product data sheet

1. General description

Dual P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low leakage current
- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Drain-source on-state resistance R_{DSon} = 1.02 Ω

3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Qu	ick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V	
V _{GS}	gate-source voltage	_		-8	-	8	V	
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-500	mA	
Static characteristics (per transistor)								
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C		-	1.02	1.4	Ω	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².

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20 V, dual P-channel Trench MOSFET

5. Pinning information

Table 2	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1		D1 D2
2	G1	gate TR1		
3	D2	drain TR2	2 5	
4	S2	source TR2		
5	G2	gate TR2		
6	D1	drain TR1	Transparent top view	S1 S2 017aaa260
7	D1	drain TR1	DFN1010B-6 (SOT1216)	
8	D2	drain TR2		

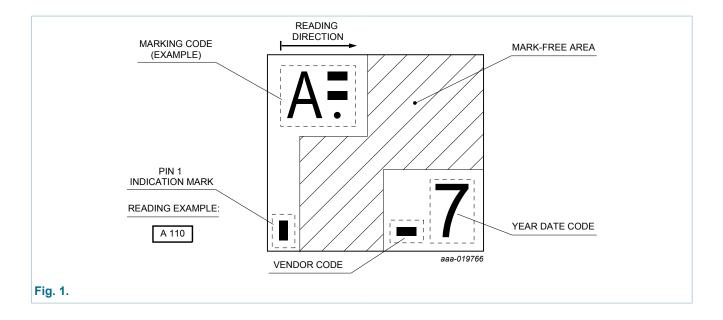
6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
PMDXB950UPEL	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216					

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMDXB950UPEL	B 111

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8. Limiting values

Table 5. Limiting values

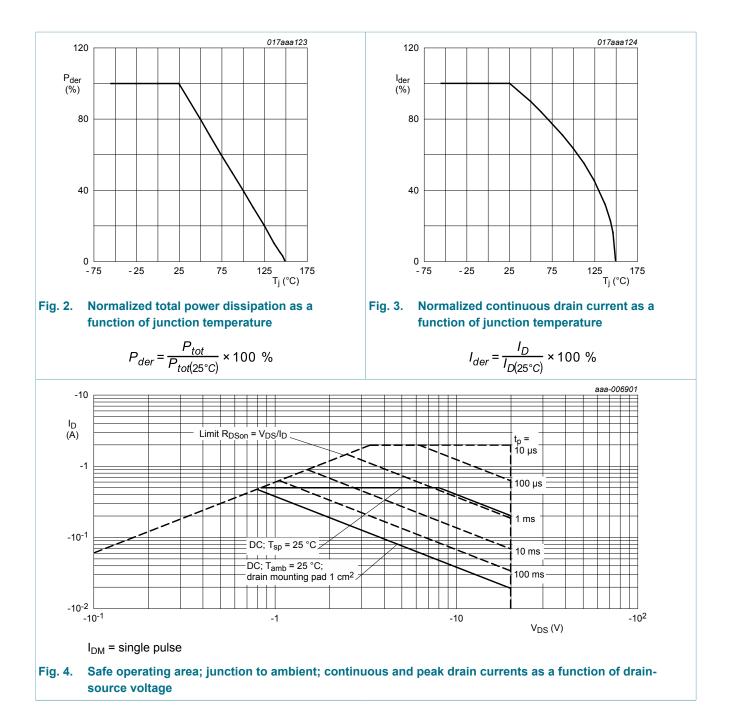
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transis	tor	· · · · · · · · · · · · · · · · · · ·				_
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-500	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-300	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-2	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	265	m٧
			[1]	-	380	mΝ
		T _{sp} = 25 °C		-	4025	m₩
Per device	I		1			
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
Is	source current	T _{amb} = 25 °C	[1]	-	-350	mA

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

20 V, dual P-channel Trench MOSFET



9. Thermal characteristics

Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
	thermal resistance	in free air	[1]	[1] -	410	475	K/W	
	from junction to ambient		[2]	-	285	330	K/W	

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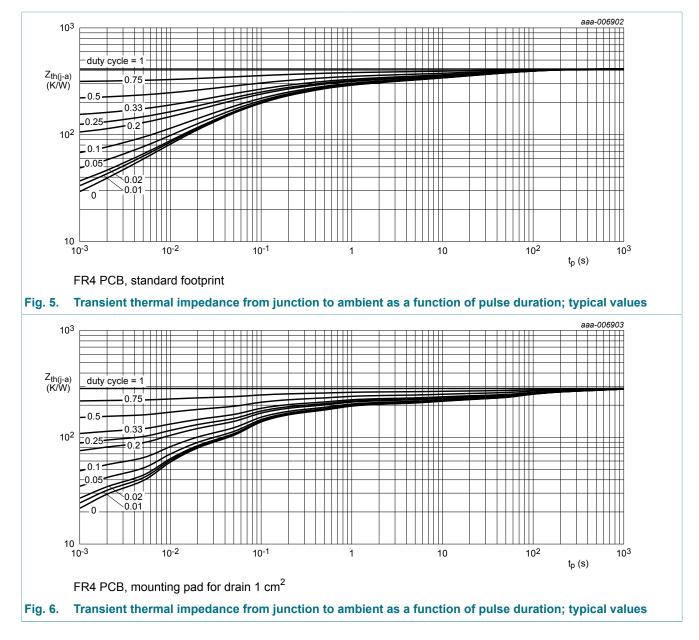
Product data sheet

20 V, dual P-channel Trench MOSFET

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		-	27	31	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



6/16

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	cteristics (per transistor)	1				
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	-10	μA
		V_{DS} = -5 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-25	nA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V _{GS} = 1.8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	50	nA
		V_{GS} = -1.8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-50	nA
Doon	drain-source on-state	V _{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C	-	1.02	1.4	Ω
	resistance	V _{GS} = -4.5 V; I _D = -500 mA; T _j = 150 °C	-	1.54	2.1	Ω
		V _{GS} = -2.5 V; I _D = -200 mA; T _j = 25 °C	-	1.27	2.2	Ω
		V _{GS} = -1.8 V; I _D = -40 mA; T _j = 25 °C	-	1.7	3.3	Ω
		V _{GS} = -1.5 V; I _D = -10 mA; T _j = 25 °C	-	2.3	5	Ω
		V _{GS} = -1.2 V; I _D = -1 mA; T _j = 25 °C	-	3.5	-	Ω
9 _{fs}	forward transconductance	V_{DS} = -10 V; I _D = -500 mA; T _j = 25 °C	-	480	-	mS
Dynamic ch	aracteristics (per transist	or)				_
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -450 mA;	-	1.19	2.1	nC
Q _{GS}	gate-source charge	V _{GS} = -4.5 V; T _j = 25 °C	-	0.17	-	nC
Q _{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	43	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	14	-	pF
C _{rss}	reverse transfer capacitance		-	8	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -0.45 A; R _L = 22 Ω;	-	2.3	-	ns
t _r	rise time	V_{GS} = -4.5 V; $R_{G(ext)}$ = 6 Ω; T_j = 25 °C	-	5	-	ns
t _{d(off)}	turn-off delay time	1 1	-	13.5	-	ns

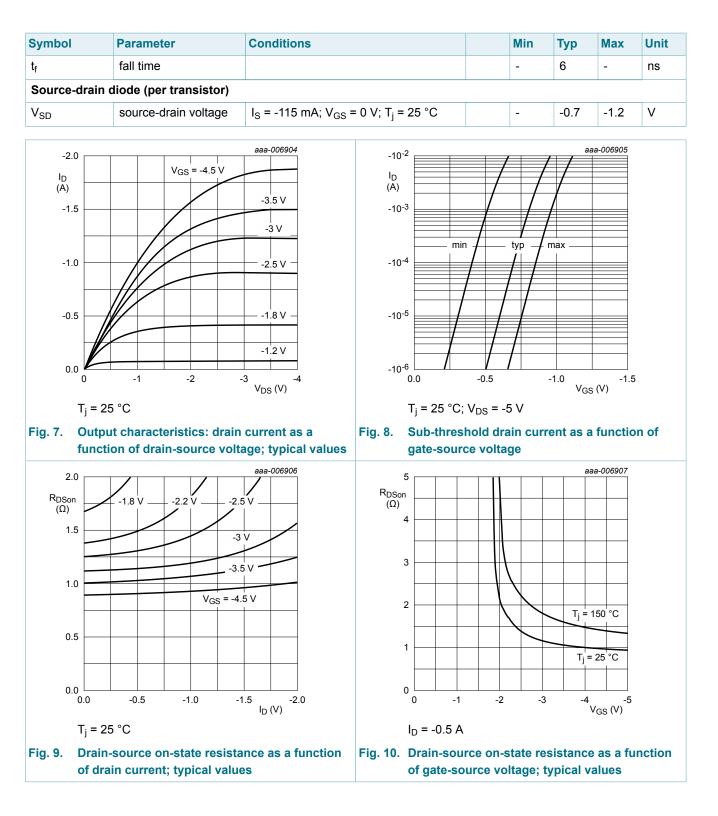
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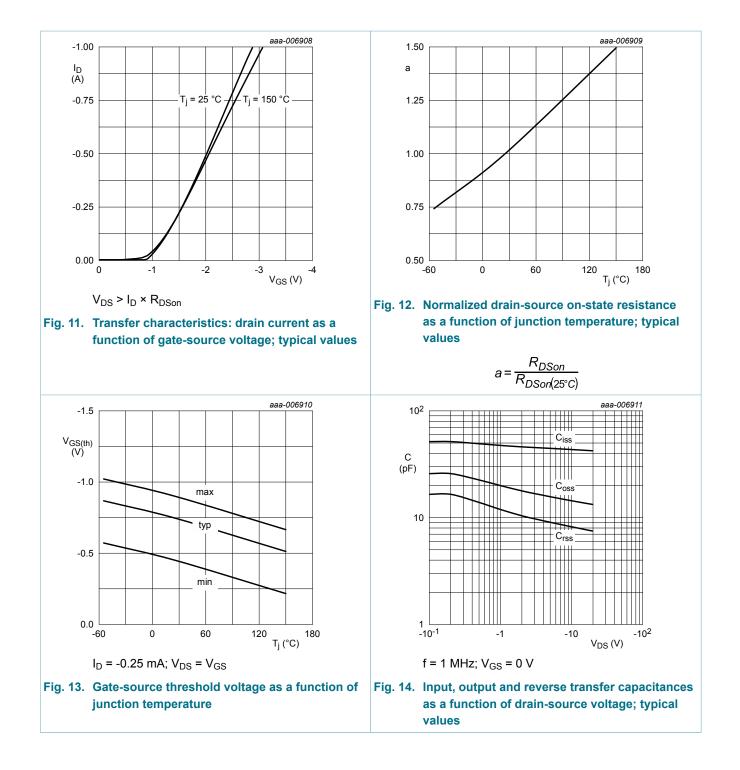
20 V, dual P-channel Trench MOSFET



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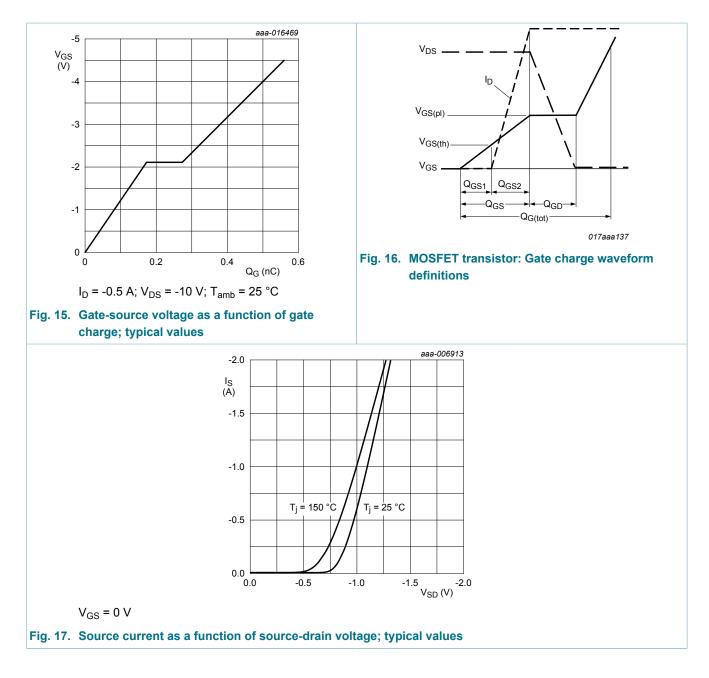
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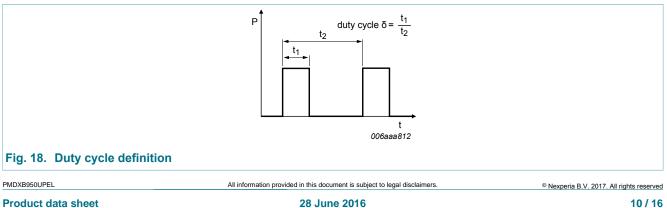
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20 V, dual P-channel Trench MOSFET



11. Test information

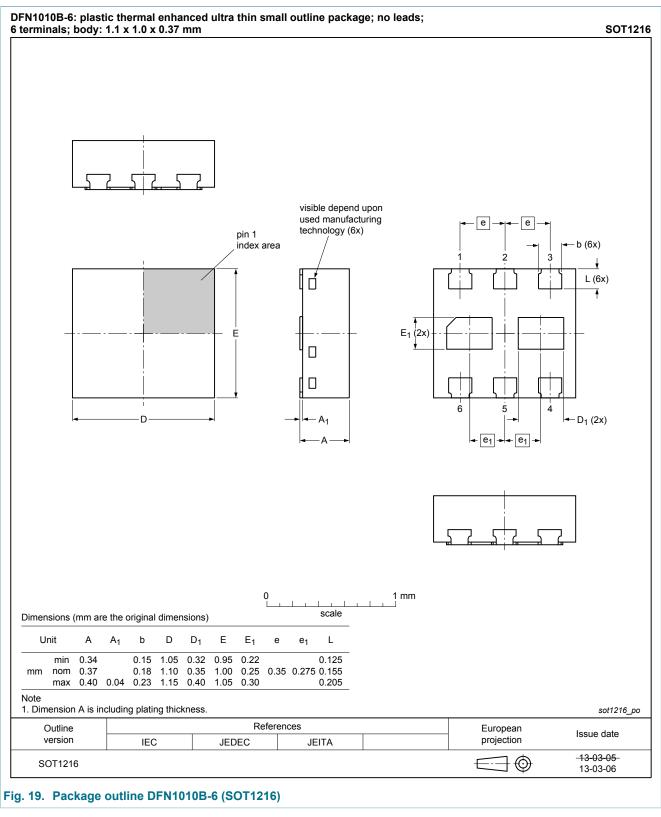


Product data sheet

28 June 2016

20 V, dual P-channel Trench MOSFET

12. Package outline



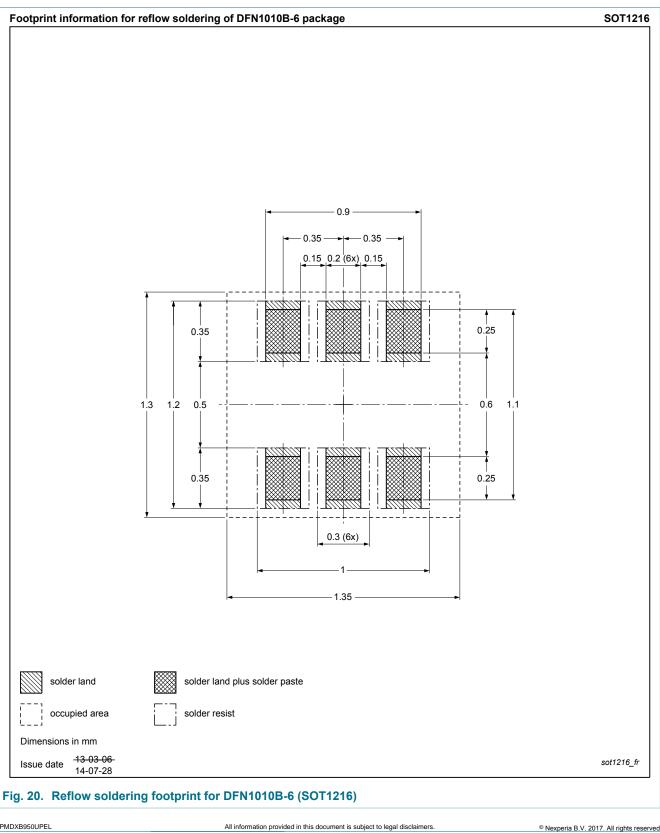
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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMDXB950UPEL v.1	20160628	Product data sheet	-	-			

20 V, dual P-channel Trench MOSFET

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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20 V, dual P-channel Trench MOSFET

16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	4
9	Thermal characteristics	5
10	Characteristics	7
11	Test information	10
12	Package outline	11
13	Soldering	12
14	Revision history	13
15	Legal information	14
15.1	Data sheet status	14
15.2	Definitions	14
15.3	Disclaimers	14
15.4	Trademarks	15

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